

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	241	257/75.ccls. 257/e51.006.ccls.	US-PGPUB; USPAT	OR	OFF	2005/11/04 08:23
L2	4991	257/40.ccls. 257/66.ccls. 257/75.ccls. 257/347.ccls. 257/e51.006.ccls. 438/99.ccls.	US-PGPUB; USPAT	OR	OFF	2005/11/04 09:01
L3	35	L2 and ((polythiophene p3ht ((conjugat\$5 organiz\$6 "self-organizable") near polymer)) same (coalesc\$6 aggregat\$6 (structur\$6 near order\$6)))	US-PGPUB; USPAT	OR	ON	2005/11/04 10:26
L4	7	(polythiophene p3ht ((conjugat\$5 organiz\$6 "self-organizable") near polymer)) same (coalesc\$6 aggregat\$6) same (structur\$6 near order\$6)	US-PGPUB; USPAT	OR	ON	2005/11/04 09:16
L5	49	((polythiophene p3ht ((conjugat\$5 organiz\$6 "self-organizable") near polymer)) and (coalesc\$6 aggregat\$6 (structur\$6 near order\$6)))	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 09:18
L6	140	((polythiophene ((conjugat\$5 organiz\$6 "self-organizable") near polymer)) same (agitat\$6 stir\$6 sonicat\$6 homogen\$10)) same (gel\$6 coat\$5 deposit\$5 layer film)	US-PGPUB; USPAT	OR	ON	2005/11/04 12:04
L7	101	(polythiophene ((conjugat\$5 organiz\$6 "self-organizable") near polymer)) and (agitat\$6 stir\$6 sonicat\$6 homogen\$10)	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 10:39
L8	2	(((((polymer with dissolv\$5) same (agitat\$6 stir\$6 sonicat\$6 homogen\$10)) same (temperature near2 (lower\$4 reduc\$6 decreas\$5 room))) same (coat\$5 deposit\$5 layer film)) same (gel\$6 near2 (avoid\$5 disrupt\$5 imped\$5 stop\$5 inhibit\$5)))	US-PGPUB; USPAT	OR	ON	2005/11/04 10:42
L9	216	((polymer with dissolv\$5 with (temperature heat\$5)) same ((agitat\$6 stir\$6 sonicat\$6 homogen\$10) with (temperature near2 (lower\$4 reduc\$6 decreas\$5 room)))) same (gel\$6 coat\$5 deposit\$5 layer film)	US-PGPUB; USPAT	OR	ON	2005/11/04 10:43

L10	109	((polymer with dissolv\$5) and (agitat\$6 stir\$6 sonicat\$6 homogen\$10)) and (temperature near2 (lower\$4 reduc\$6 decreas\$5 room))) and (gel\$6 coat\$5 deposit\$5 layer film)	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 10:53
L11	27	((polymer with dissolv\$5 with (temperature heat\$5)) same ((sonicat\$6 homogen\$10) with (temperature near2 (lower\$4 reduc\$6 decreas\$5 room)))) same (gel\$6 coat\$5 deposit\$5 layer film)	US-PGPUB; USPAT	OR	ON	2005/11/04 10:55
L12	27	((polymer with dissolv\$5 with (temperature heat\$5)) same ((sonicat\$6 homogen\$10) with stir\$6 with (temperature near2 (lower\$4 reduc\$6 decreas\$5 room))))	US-PGPUB; USPAT	OR	ON	2005/11/04 10:59
L13	49	(polymer with dissolv\$5 with (temperature heat\$5)) same (water alcohol liquid) same ((coat\$5 deposit\$5 layer film) with spin\$6)	US-PGPUB; USPAT	OR	ON	2005/11/04 11:02
L14	16	(polymer with thixotrop\$8 with gel\$8) same (agitat\$6 stir\$6 sonicat\$6 homogen\$10)	US-PGPUB; USPAT	OR	ON	2005/11/04 11:07
L15	71	(polythiophene conjugat\$5 organiz\$6 "self-organizable") with (polyphosphazene phosphazene)	US-PGPUB; USPAT	OR	ON	2005/11/04 11:11
L16	208	L2 and ((polythiophene p3ht ((conjugat\$5 organiz\$6 "self-organizable") near polymer)) with semiconductor)	US-PGPUB; USPAT	OR	ON	2005/11/04 11:15
L17	280	L2 and ((polythiophene p3ht ((conjugat\$5 organiz\$6 "self-organizable") near polymer)) with semiconduct\$6)	US-PGPUB; USPAT	OR	ON	2005/11/04 11:30
L18	208	L2 and ((polythiophene p3ht ((conjugat\$5 organiz\$6 "self-organizable") near polymer)) with semiconductor)	US-PGPUB; USPAT	OR	ON	2005/11/04 11:47
L19	280	L2 and ((polythiophene p3ht ((conjugat\$5 organiz\$6 "self-organizable") near polymer)) with semiconduct\$6)	US-PGPUB; USPAT	OR	ON	2005/11/04 11:47
L20	72	L19 not L18	US-PGPUB; USPAT	OR	ON	2005/11/04 11:47

L21	35	L2 and ((polythiophene p3ht ((conjugat\$5 organiz\$6 "self-organizable") near polymer)) same (coalesc\$6 aggregat\$6 (structur\$6 near order\$6)))	US-PGPUB; USPAT	OR	ON	2005/11/04 11:51
L22	246	((polythiophene p3ht ((conjugat\$5 organiz\$6 "self-organizable") near polymer)) with (coalesc\$6 aggregat\$6 (structur\$6 near order\$6)))	US-PGPUB; USPAT	OR	ON	2005/11/04 11:54
L23	20	((polythiophene ((conjugat\$5 organiz\$6 "self-organizable") near polymer)) and (gel\$6 coalesc\$6 aggregat\$6) and (tft (semiconductor near2 (film layer)) (thin adj film adj transistor) (gate with (source drain electrode))))). clm.	US-PGPUB	OR	ON	2005/11/04 12:09